


	<h2 style="color: red;">JAN1N5622US</h2>	
	<b>Manufacturer Part Number:</b>	<a href="#">JAN1N5622US</a>
	<b>Manufacturer/Brand:</b>	<a href="#">Microsemi</a>
	<b>Part of Description:</b>	DIODE GEN PURP 1KV 1A D5A
<p>Image may be representation. See specs for product details.</p>	<b>Datasheets:</b>	 <a href="#">JAN1N5622US.pdf</a>
	<b>RoHs Status:</b>	Contains lead / RoHS non-compliant
	<b>Stock Condition:</b>	New original, Stock Available.
	<b>Ship From:</b>	Hong Kong
	<b>Shipment Way:</b>	DHL/Fedex/TNT/UPS/EMS









### Specifications

Part Number	JAN1N5622US
Manufacturer	Microsemi
Description	DIODE GEN PURP 1KV 1A D5A
Category	Discrete Semiconductor Products > Diodes - Rectifiers -
Part Status	<a href="#">Require For Quote &amp; Check Stock</a>
Voltage - Forward (Vf) (Max) @ If	1.3V @ 3A
Voltage - DC Reverse (Vr) (Max)	1000V (1kV)
Supplier Device Package	D-5A
Speed	Standard Recovery >500ns, > 200mA (Io)
Series	Military, MIL-PRF-19500/427
Reverse Recovery Time (trr)	2µs
Packaging	Bulk
Package / Case	SQ-MELF, A
Operating Temperature - Junction	-65°C ~ 200°C
Mounting Type	Surface Mount
Diode Type	Standard
Current - Reverse Leakage @ Vr	500nA @ 1000V
Current - Average Rectified (Io)	1A
Capacitance @ Vr, F	-

JAN1N5622US Electronic Components is 100% New Original from YIC Distributor, Search JAN1N5622US Datasheets, PDF, Inventory at Y-IC.com Online, Order JAN1N5622US Microsemi with Warrantied and Confidence. Ship by DHL/FedEx/TNT/UPS Express. Support Payment with Telegraphic Transfer(T/T) or PayPal.  
RFQ JAN1N5622US Email: [Info@Y-IC.com](mailto:Info@Y-IC.com)

### You May Be Also Be interested

In:

  <b>JAN1N5635A</b> Microsemi Corporation TVS DIODE 10.2VWM 16.7VC DO13	  <b>JAN1N5621US</b> Microsemi Corporation DIODE GEN PURP 800V 1A D5A	  <b>JAN1N5622</b> Microsemi Corporation DIODE GEN PURP 1KV 1A AXIAL	  <b>JAN1N5623</b> Microsemi Corporation DIODE GEN PURP 1KV 1A AXIAL
  <b>JAN1N5620US</b> Microsemi Corporation DIODE GEN PURP 800V 1A D5A	  <b>JAN1N5621</b> Microsemi Corporation DIODE GEN PURP 800V 1A AXIAL	  <b>JAN1N5629A</b> Microsemi Corporation TVS DIODE 5.8VWM 10.5VC DO13	  <b>JAN1N5621</b> Microsemi Corporation DIODE GEN PURP 800V 1A AXIAL

### Related Hot keyword More

JAN1N5622US Microsemi	JAN1N5622US Data Sheet	JAN1N5622US Datasheets	JAN1N5622US PDF	Microsemi JAN1N5622US
JAN1N5622US Electronic	JAN1N5622US Components	JAN1N5622US Distributor	JAN1N5622US Image	JAN1N5622US Part
JAN1N5622US Price	JAN1N5622US Manufacturer	JAN1N5622US Picture	JAN1N5622US Stock	JAN1N5622US Inventory
JAN1N5622US New	JAN1N5622US Original	JAN1N5622US Warranted	JAN1N5622US RFQ	JAN1N5622US Order Online